

### MAINTENANCE MANUAL

LBI31004C

# TRANSMITTER/RECEIVER BOARD 19D900232G2, G3 & G4-G6

#### GE MARC V

### 19D900742G5, 6

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#### DESCRIPTION

The transmitter/receiver board contains the fixed tuned power amplifier module, power control circuit and the 800 MHz receiver. Component parts for the exciter are located on the synthesizer/ interconnect board and the transmitter/ receiver board. The frequency synthesizer and frequency injection chain including a frequency tripler are located on the synthesizer/interconnect board. The transmitter/receiver board is mounted on the bottom side of the "H" frame chassis.

The exciter provides approximately 250 milliwatts of modulated RF power to the PA module which provides 15 watts power output. Figure 1 is a block diagram of the GE MARC V radio showing both the transmitter and receiver.

#### TRANSMITTER

### EXCITER

The synthesized frequency output and the injection output from the interconnect/frequency synthesizer board are applied to the balanced mixer through J101 and J102. The mixer output signal is the sum of these two input signals and will fall within the range of 408-410.5 MHz. The output of the balanced mixer is coupled through three tuned circuits (L101, L102, L103) to the base of amplifier Q101. Metering test point TP101 is used in tuning L101, L102 and L103. The typical DC reading is 5.6 volts.

#### CIRCUIT ANALYSIS

Following amplifier Q101 is frequency doubler Q102. The output of allows the RF output power to be set to 102 (816-821 MHz) is filtered by L107.

L108, and L109, and are tuned to the operating frequency. The filter output is applied to the base of amplifier Q103.

The collector output of Q103 is applied to a power splitter consisting of L111 and C116, and L112 and C121. The portion of the RF signal coupled through L111 and C116 is applied to the base of amplifier Q104. The output of Q104 is coupled to the receiver and used as the 1st oscillator injection frequency. The signal coupled through L112 and C121 is applied to the base of exciter amplifier Q105. The collector tank of Q105 is tuned by C125 and C127.

Following Q105 is amplifier Q106. The output of Q106 is tuned by C133 and C134.

Variable capacitors C125, C127, C133 and C134 are tuned for a maximum DC voltage reading at TP103. The typical DC reading at TP103 is 1.6 volts. Part of the RF signal at W102 is rectified by "sniffer" diode D101 to provide the voltage reading at TP103.

W102 is a 50 ohm stripline on the printed circuit board that matches the exciter output to the PA input impedance.

## POWER AMPLIFIER

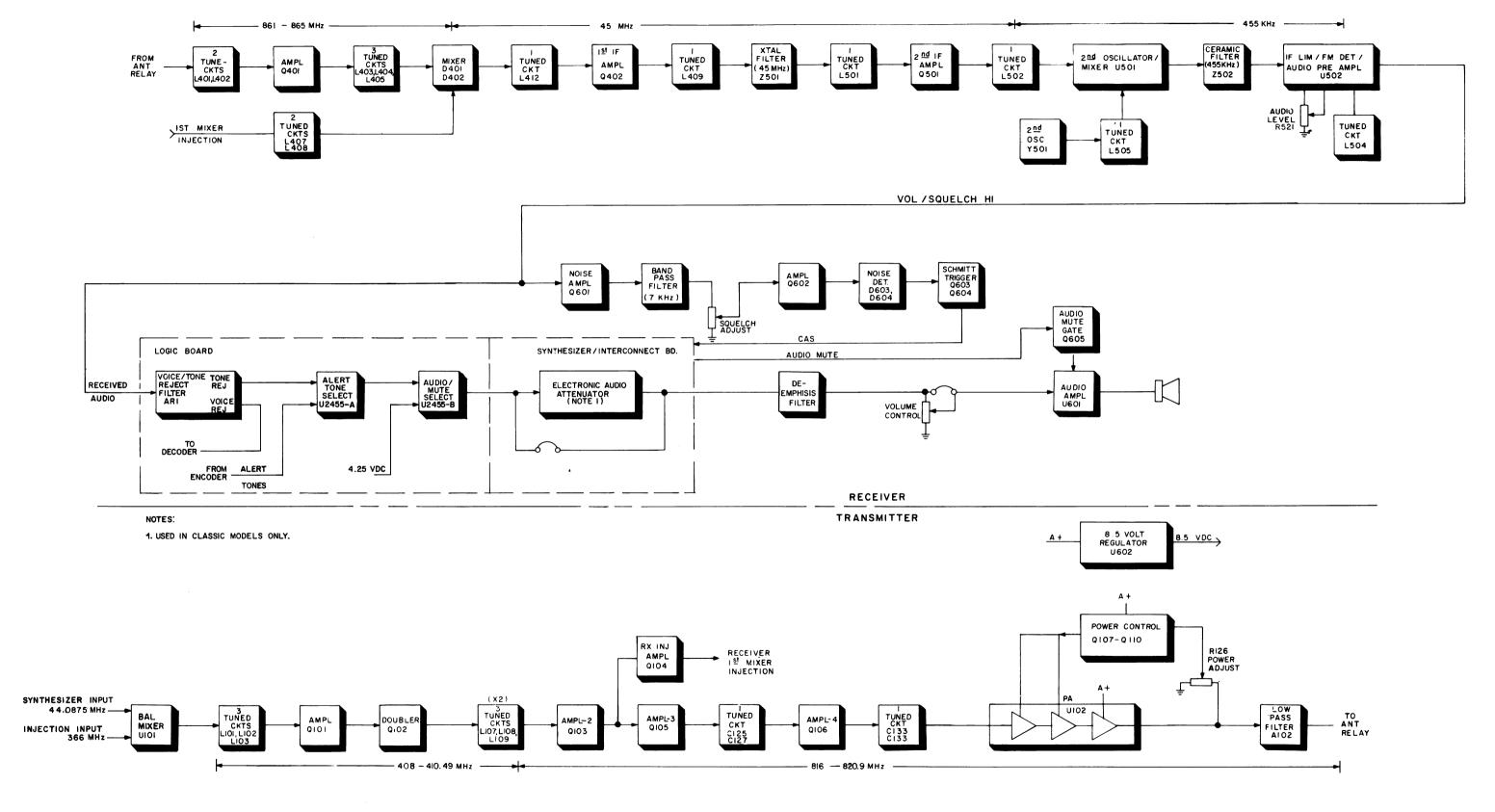
Power amplifier U102 is a three stage amplifier that amplifies the 250 milliwatt exciter output to provide a 15 watt output. The output of U102 is coupled through 50 ohm stripline W104 to low pass filter A102. The filter output is applied to antenna relay K601.

# RF POWER CONTROL CIRCUIT

The output power adjust circuit rated output power. The power adjustment



1



RC 4147

is attained by controlling the DC collector voltage to the pre-driver and driver stages in U102 through pass transistor Q110. The pass transistor is controlled by a feedback loop consisting of Q107 through Q109. The power is set by potentiometer R126.

Any change in output power is sensed by the power control circuit. For example: if the output power increases, more RF is rectified by D102, increasing the base voltage of Q107. This causes Q107 to conduct more, reducing its collector voltage (and base voltage to Q108).

Reducing the base voltage applied to Q107 causes it to conduct less, raising the base voltage of PNP transistor Q109. With Q109 conducting less, there is less base voltage applied to pass transistor Q110 resulting in less collector voltage being applied to the pre-driver and driver stages in U102. This reduces the output power of the PA module in proportion to the increase in output power detected at the base of Q107. TP104 is used to check the DC control voltage being applied to the power amplifier; typically this voltage is 9.0 VDC.

#### RECEIVER

GE MARC V 800 MHz receivers are dual conversion, superheterodyne FM receivers designed for operation in the 861-865 MHz frequency range. A regulated 8.5 volts is used for all receiver stages except for the audio PA IC, which operates from the A+ supply.

The receiver uses intermediate frequencies of 45 MHz and 455 kHz. Adjacent channel selectivity is obtained by using two bandpass filters: a 45 MHz crystal filter and a 455 kHz ceramic filter.

All receiver circuitry is mounted on the transmitter/receiver Tx/Rx) board. The receiver consists of:

- Receiver Front End and 1st Mixer
- 45 MHz 1st IF circuitry
- 2nd Oscillator
- 455 kHz 2nd IF circuitry with FM Detector
- Audio PA Circuit
- Squelch Circuit

## RECEIVER FRONT END

RF from the antenna is coupled through two helical resonators (L401 and

L402) to the base of RF amplifier Q401. Q401 is a class A, common emitter amplifier that provides a gain of approximately 8 to 10 dB. The amplified output is coupled through three additional helicals to the 1st mixer. The five helicals provide the front end selectivity.

#### 1ST MIXER

The 1st mixer is a dual balanced diode mixer that converts a signal in the 861--865 MHz range to the 45 MHz 1st IF frequency.

RF from the front end helicals is coupled through C404 to mixer diodes D401 and D402. The low side injection input from the exciter is coupled through two helicals (L407 and L408) to the mixer diodes. The injection input port is isolated from the RF input and IF output by a balancing transformer consisting of L413 tapped to ground.

The 1st mixer output is coupled through a tuned circuit (L412 and C405) that matches the mixer output to gate 1 of 1st IF amplifier Q402.

TP401 is used in tuning the discrete IF stages and the injection filter, L408 and L409.

## 1ST IF AMPLIFIER AND FILTER

IF Amplifier Q402 is a dual gate FET that provides good intermodulation and desensitization characteristics. The amplifier also acts as a buffer between the variable balanced mixer output impedance and the crystal filter.

The 45 MHz output signal at the drain of Q402 is coupled through a tuned circuit (L409 and C408) that sets the impedance to crystal filter Z501.

Z501 is a 45 MHz, four-pole crystal filter that provides a minimum of 30 dB adjacent channel rejection. The filter output is applied through a tuned circuit (L501, C501 and C526) that matches the output impedance of Z501 to the second IF amplifier.

## 2ND IF AMPL

2nd IF Amplifier Q501 is a dual-gate FET. The filter output is applied to Gate 1 of the amplifier, and the output is taken from the drain. The biasing on Gate 2 and the drain load determines the gain of the stage. The amplifier provides approximately 20 dB of IF gain. The output of Q501 is coupled through L502 which matches the amplifier output to the input of IC U501.

2ND OSC/MIXER AND IF AMPL

The 2nd oscillator, mixer and 3rd IF amplifier consists of U501 and associated circuitry. The oscillator operates at 45.455 MHz for high side injection (45.4675 MHz-offset IF). The oscillator crystal is Y501. The 45 MHz input frequency is mixed with the oscillator frequency to provide the 2nd IF frequency of 455 kHz. Diodes D501 and D502 limit the mixer output. L503 is tuned for the 2nd IF output of 455 kHz.

## FILTER, LIMITER AND DETECTOR

The output of U501 is coupled through ceramic filter Z502 which provides the 455 kHz selectivity, and applied to U502. Test Point TP501 is used in aligning the receiver, and can be used to check the output of U501. The typical DC reading at TP501 is 2.7 volts.

U502 and associated circuitry consists of a 455 kHz limiter, a quadrature-type FM detector and an audio pre-amplifier. L504 is the quadrature detector coil. Audio Level Potentiometer R521 is used to set the audio output level to the audio amplifier.

#### AUDIO AND SQUELCH CIRCUITS

### Audio

Audio from the audio pre-amplifier U502 is applied to the voice/tone reject filter in the logic board through J903-3 and J2502-3 on the synthesizer/interconnect board. The voice/tone reject filter removes the busy tone and applies the received audio to the alert tone switch. The alter tone switch under control of the microprocessor selects either alert tones or voice frequencies to apply to the audio mute switch. The audio mute switch, under control of the microprocessor completes the audio path to the de-emphasis network.

On GE-MARC V CORONA and CENTURA trunked mobile radios, the audio passes through the de-emphasis network (R901 on the interconnect board, R629, C607 and C608) to volume control R630.

On GE-MARC V Classic radios the audio from the audio/mute select switch is applied to the electronic audio attentuator. The electronic audio attentuator under control of the microprocessor controls the audio level applied to the

audio amplifier and replaces the volume control potentiometer found in the GE-MARC V CORONA and CENTURA Radios. Audio from the electronic attentuator is applied to the audio amplifier through the de-emphasis network.

The audio amplifier IC (U601) drives the speaker (or handset) at the desired audio level. The feedback loop containing R633, R634, and C610 determines the amplifiers closed loop gain. R631 and C612 provide the high audio frequency roll-off above 6 kHz.

## Squelch

The squelch circuit operates on the noise components contained in the FM detector output. The output of U502 is applied to frequency selective noise amplifier Q601 that has a resonant circuit (L601, R604 and C602) as the collector load. The output is noise in a band around 7 kHz.

This noise output is coupled through Squelch control R607 to expander amplifier Q602 which improves the level discrimination characteristics of the circuit. The output of Q602 is applied to a passive voltage doubler circuit (D603 and D604). This circuit has a high source impedance an operates as an average value rectifier.

Following the voltage doubler is a Schmidt Trigger (Q603 and Q604). The Schmidt Trigger provides the necessary hysteresis and a well-defined output signal for Rx mute gate Q605.

With no RF signal present, the detected noise at the voltage doubler output turns on Q603, turning off Q604. This causes Q605 to turn on, applying +1.7 volts to pin 2 of audio amplifier U601. This voltage turns off U601 and mutes the receiver.

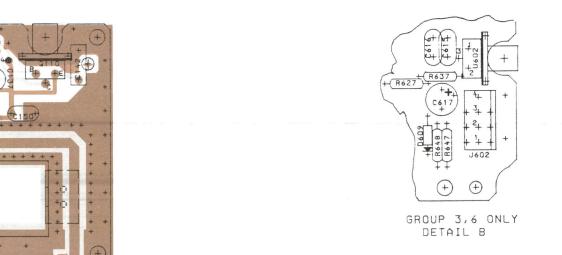
When an RF signal is received, the noise at the output of Q601 decreases and drive to Q603 is removed. This turns off Q603 and allows Q604 to turn on. With Q604 turned on, Rx mute gate Q605 turns off. This turns on U601 so that audio is heard at the speaker.

The squelch sensitivity is adjusted by R607 in the base circuit of expander amplifier Q602.

Pressing in the SQUELCH pushbutton on the front of the radio grounds the base of Q601 and disables the squelch function (and Channel Guard if present).

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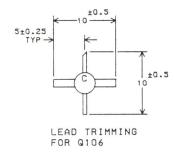
19D900232G REV

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SONETCH

POWER

(#)



LEAD IDENTIFICATION FOR Q101-Q105 & Q401



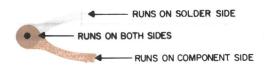
TOP VIEW NOTE: COLLECTOR LEAD MARKED WITH BODY DOT AS SHOWN.

LEAD IDENTIFICATION FOR Q601,Q602,Q603,Q604 & Q605 Q107,Q108,Q109



TOP VIEW

NOTE. CASE SHAPE IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

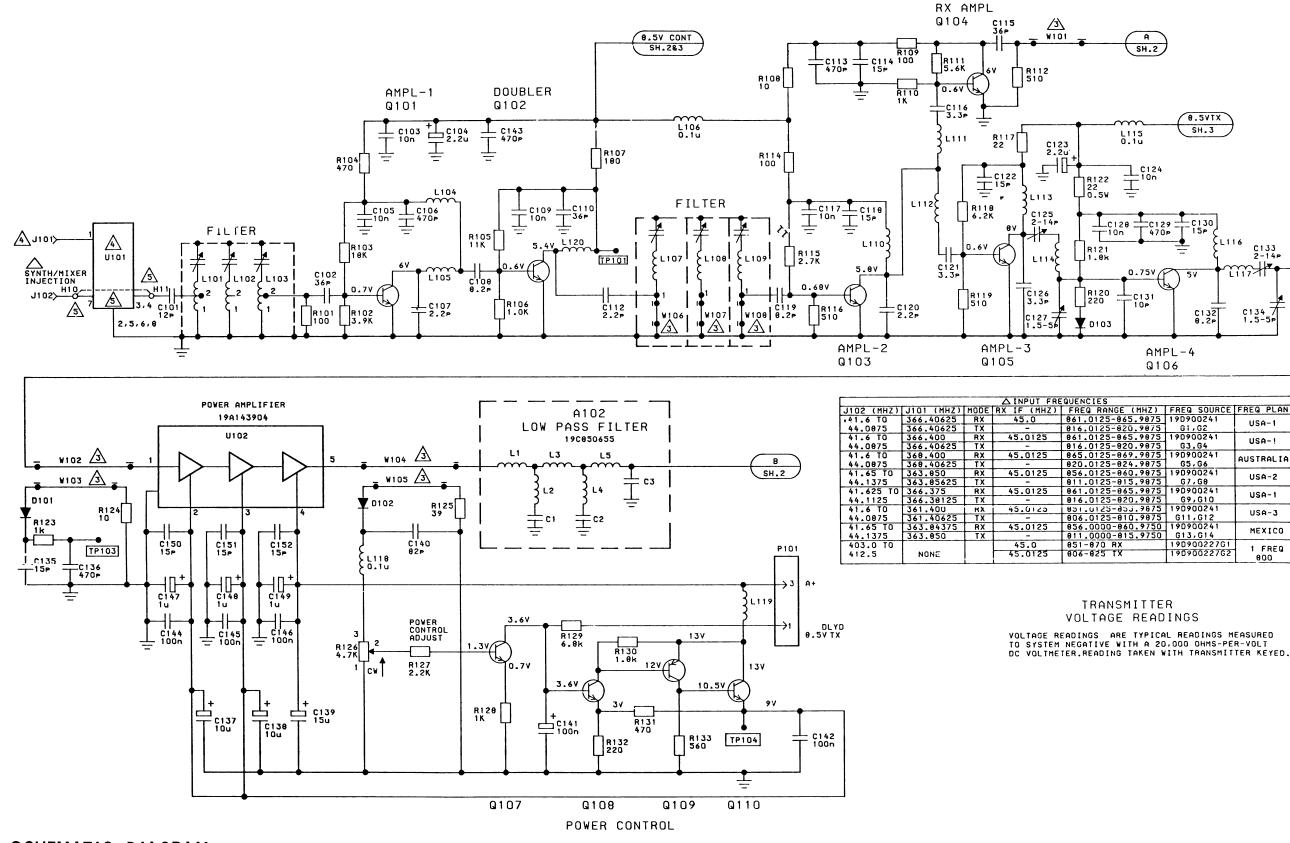


# OUTLINE DIAGRAM

TRANSMITTER/RECEIVER BOARD

Issue 3

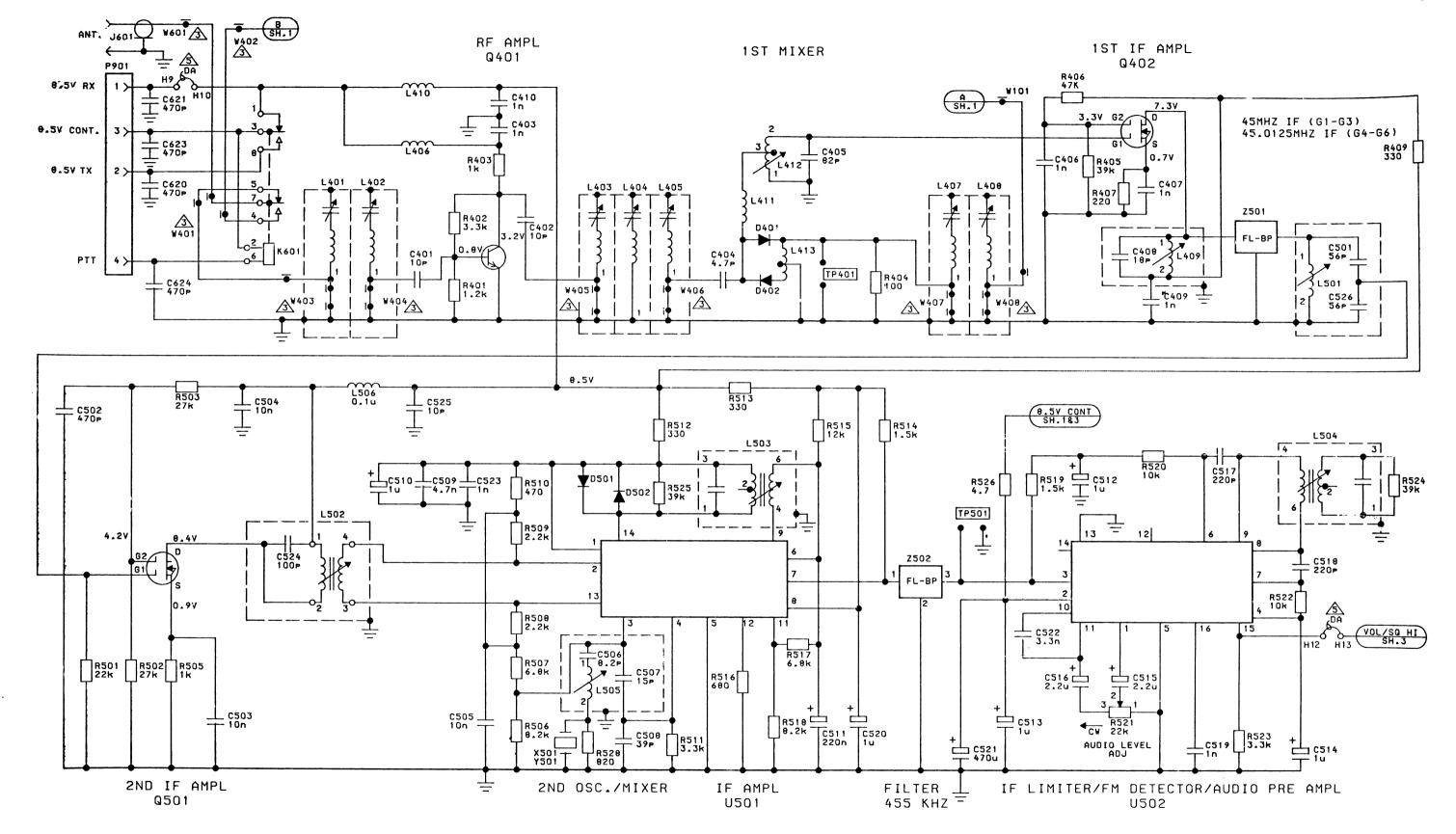




# SCHEMATIC DIAGRAM

TRANSMITTER

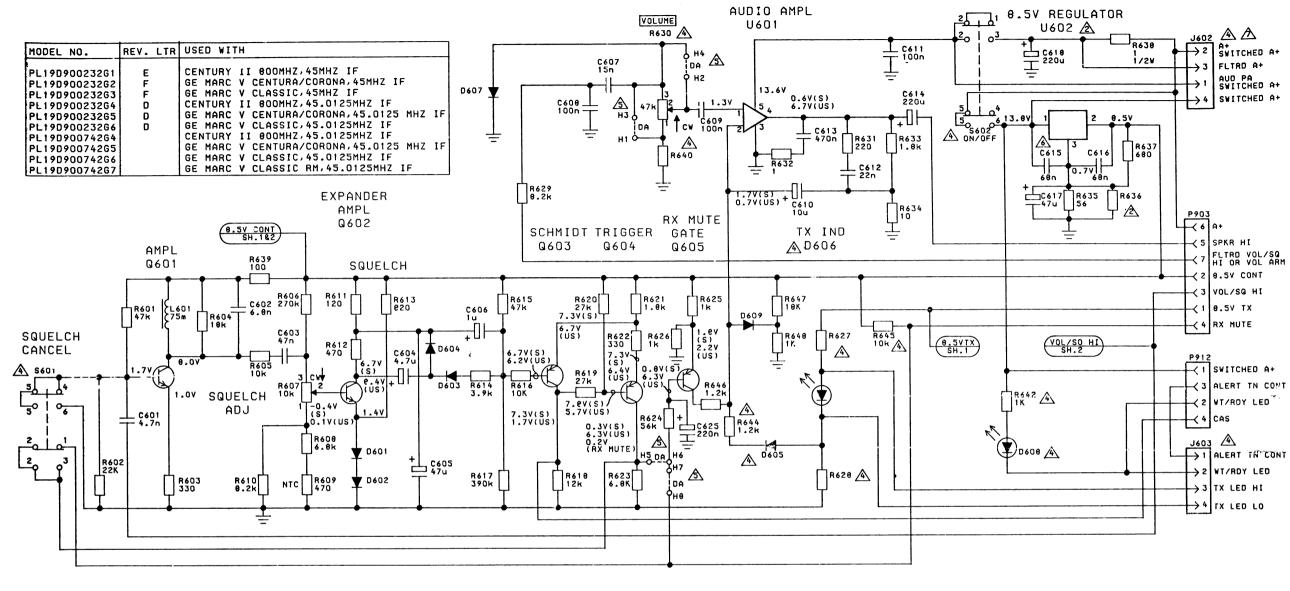
(19D900348, Sh. 1, Rev. 11)



(19D900348, Sh. 2, Rev. 4)

# SCHEMATIC DIAGRAM

RECEIVER



VALUE OF R636 DEPENDS ON COLOR CODE ON U602.

U602 COLOR VALUE O OMIT R636

A PART OF PRINTED CIRCUIT BOARD.

4	COMPONENT VALUES	
G1 & G4	G2 & G5	G3 & G6
800MHZ 1 FREG	GE MARC V	GE MARC V
L	CENTURA/CORONA	CLASSIC
D605	OMIT	OMIT
De06	D606	OMIT
OMIT	D608	OMIT
OMIT	J101	J101
OMIT	OMIT	J602
OMIT	OMIT	J603
R627A 220	R627A 220	R627B 150
R620A 150	R628A 150	R628B 180
R630	R630	OMIT
R640A 10	R640B 2.2K	R640C 47K
OMIT	R642	TIMO
\$601	TIMO	OMIT
\$602	\$602	OMIT
OMIT	U101	U101
P644	OMIT	OMIT
OMIT	R645	R645

DA JUMPER PRESENT H5 TO H6 IN G1 & G4 ONLY. DA JUMPER PRESENT H7 TO H8 IN 62,63,65 & 66 ONLY.

DA JUMPER PRESENT H10 TO H11 IN 61 & 64 ONLY.

DA JUMPER PRESENT H1 TO H3.H2 TO H4 IN 63 & 66 ONLY.

DA JUMPER PRESENT H9 TO H10.H12 TO H13 IN 61-66 ONLY.

ALL RESISTORS ARE 1/4 WATT UNLESS OTHERWISE SPECIFIED. RESISTOR VALUES IN A UNLESS FOLLOWED BY MULTIPLIER & OR M. CAPACITOR VALUES IN F UNLESS FOLLOWED BY MULTIPLIER u, n OR P. INDUCTANCE VALUES IN H UNLESS FOLLOWED BY MULTIPLIER m OR u.

### RECEIVER **VOLTAGE READINGS**

VOLTAGE READINGS ARE TYPICAL READINGS MEASURED TO SYSTEM NEGATIVE WITH A 20,000 OHMS-PER-VOLT DC VOLTMETER UNDER THE FOLLOWING CONDITIONS:

- 3. SQUELCH CANCEL (\$601) SWITCHED OFF 4. UNSQUELCHED (US)-SQUELCH ADJUST (R607)

# SCHEMATIC DIAGRAM

RECEIVER

Issue 4

1. NO SIGNAL INPUT
2. VOLUME CONTROL (R630) SET TO MINIMUM

5. SQUELCHED (S)-SQUELCH ADJUST (R607) SET

TO MAXIMUM (CCM)

C615 PRESENT IN GP.1 & GP.4.

FOR TRUNK MOUNT RADIO, J602-2 IS SWITCHED A+ INPUT FROM CONTROL UNIT.

# PARTS LIST

TRANSMITTER/RECEIVER

19D900232G3 GE MARC V CORONA & CENTURA (45 MHz IF) REV G
19D900232G5 GE CORONA & CENTURA (45.0125 MHz IF) REV E
19D900232G6 GE CORONA & CENTURA (45.0125 MHz IF) REV E
1SSUE 2

	GE PART NO.	DESCRIPTION
A102		LOW PASS FILTER BOARD 19C850655G1
L3	19A701782P1	Coil.
L5	19A701782P1	Coil.
C101	19A700219P30	Ceramic: 12 pF ±5%, 100 VDCW, temp coef 0 PPM.
C102	19A700219P48	Ceramic: 36 pF ±5%, 100 VDCW, temp coef 0 PPM.
C103	19A700234P7	Polyester: 0.01 uF ±10%, 50 VDCW.
C104	19A701534P5	Tantalum: 2.2 uF, <u>+</u> 20%, 35 VDCW.
C105	19A116192P1	Ceramic: 0.01 uF $\pm 20\%$ , 50 VDCW; sim to Erie 8121 SPECIAL.
C106	19A116192P2	Ceramic: 470 pF $\pm 20\%$ , 50 VDCW; sim to Erie 811-A050-W5R-471 $\dot{M}$ .
C107	19A700219P10	Ceramic: 2.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C108	19A700219P24	Ceramic: 8.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C109	19A116192P1	Ceramic: 0.01 uF ±20%, 50 VDCW; sim to Erie 8121 SPECIAL.
C110	19A700219P48	Ceramic: 36 pF ±5%, 100 VDCW, temp coef 0 PPM.
C112	19A700219P10	Ceramic: 2.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C112	19A700219P48	Ceramic: 36 pF ±5%, 100 VDCW, temp coef 0 PPM.
C114	19A700219P33	Ceramic: 15 pF ±5%, 100 VDCW, temp coef 0 PPM.
C115	19A700219P48	Ceramic: 36 pF ±5%, 100 VDCW, temp coef 0 PPM.
C116	19A700219P14	Ceramic: 3.3 pF ±5%, 100 VDCW, temp coef 0 PPM.
C117	19A116192P1	Ceramic: 0.01 uF ±20%, 50 VDCW; sim to Erie 8121 SPECIAL.
C118	19A700219P33	Ceramic: 15 pF ±5%, 100 VDCW, temp coef 0 PPM.
C119	19A700219P24	Ceramic: 8.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C120	19A700219P10	Ceramic: 2.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C121	19A700219P14	Ceramic: 3.3 pF ±5%, 100 VDCW, temp coef 0 PPM.
C122	19A700219P33	Ceramic: 15 pF ±5%, 100 VDCW, temp coef 0 PPM.
C123	19A701534P5	Tantalum: 2.2 uF, ±20%, 35 VDCW.
C124	19A700234P7	Polyester: 0.01 uF +10%, 50 VDCW.
C125	19A700008P2	Variable: 2.28 to 14.13 pF; sim to EF Johnson 187-0109-005.
C126	19A700219P14	Ceramic: 3.3 pF ±5%, 100 VDCW, temp coef 0 PPM.
C127	19A700008P3	Variable, air: 1.56 to 4.86 pF; sim to EF Johnson 187-0103-005.
C128	19A116192P1	Ceramic: 0.01 uF ±20%, 50 VDCW; sim to Erie 8121 SPECIAL.
C129	19A116192P2	Ceramic: 470 pF ±20%, 50 VDCW; sim to Erie 811-A050-W5R-471M.
C130	19A700219P33	Ceramic: 15 pF ±5%, 100 VDCW, temp coef 0 PPM.
C131	19A700219P26	Ceramic: 10 pF ±5%, 100 VDCW, temp coef 0 PPM.
C132	19A700219P24	Ceramic: 8.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C133	19A700008P2	Variable: 2.28 to 14.13 pF; sim to EF Johnson 187-0109-005.
	19A700008P3	Variable, air: 1.56 to 4.86 pF; sim to EF Johnson 187-0103-005.

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
C135	19A700219P33	Ceramic: 15 pF ±5%, 100 VDCW, temp coef 0 PPM.	C602	19A700234P6	Polyester: 6800 pF ±10%, 50 VDCW.	L105	19J706085P8	Coil, RF: 0.110 uH ind., ±5%; sim to Paul Smith
C136	19A116655P14	Ceramic disc: 470 pF ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C603	19A700234P11	Polyester: 0.047 uF ±10%, 50 VDCW.	L106	19B209420P101	Coil, RF: .10 uH +10%, 0.8 ohms DC res max; sim
C137	19A701534P7	Tantalum: 10 uF ±20%, 16 VDCW.	C604	19A701534P6	Tantalum: 4.7 uF ±20%, 35 VDCW.		1000000000	to Jeffers 4416-1K.
and C138		1	C605 C606	19A134730P1 19A701534P4	Electrolytic: 47 uF +100 -10%, 16 VDCW.	L107 thru L109	19B233593P4	Coil, RF: sim to Paul Smith SK-832-1.
C139	19A701225P1	Electrolytic: 15 uF -10 +75%, 25 VDCW; sim to Sprague 501D156-G025BB1C.	C607	19A701334P4 19A700234P8	Tantalum: 1 uF ±20%, 35 VDCW.  Polyester: .015 uF ±10%, 50 VDCW; sim to NISSEI	L110	19A701524P1	Coil.
C140	19A700006P32	Mica: 82 pF ±5%, 100 VDCW; sim to Underwood			AMXV or AMZV.	L111	19A701524P5	Coil.
		3HS0020.	C608 and	19A700234P13	Polyester: 0.1 uF ±10%, 50 VDCW.	L112	19A701524P2	Coil.
C141 C142	19A701534P1 19A700004P2	Tantalum: 0.1 uF ±20%, 35 VDCW.  Metallized polyester: 0.1 uF ±10%, 63 VDCW.	C607 C610	19A701534P7	Tantalum: 10 uF +20%, 16 VDCW.	L113	19A701524P3	Coil.
C142 C143	19A116192P2	Ceramic: 470 pF ±20%, 50 VDCW; sim to Erie	C611	19A700234P13	Polyester: 0.1 uF ±10%, 50 VDCW.	L114	19A701524P1	Coil.
		811-A050-W5R-471M.	C612	19A702250P113	Polyester: 0.1 uF ±10%, 50 VDCW.	L115	19B209420P101	Coil, RF: .10 uH ±10%, 0.8 ohms DC res max; sim to Jeffers 4416-1K.
C144 thru	19A143565P8	Ceramic: 0.1 uF ±10%, 50 VDCW.	C613	19A700004P6	Metallized Polyester: 0.47 ±10%, 63 VDCW.	L116	19A701524P4	Coil.
C146 C147	19A701534P4	Tantalum: 1 uF ±20%, 35 VDCW.	C614	19A134730P2	Electrolytic: 220 uF +100 -10%, 25 VDCW.	L117	19A701524P1	Coil.
thru C149	194701334F4	Tantarum. Tur _20%, 50 Thew.	C615 and	19A700234P12	Polyester: 0.068 uF ±10%, 50 VDCW.	L118	19B209420P101	Coil, RF: .10 uH ±10%, 0.8 ohms DC res max; sim to Jeffers 4416-1K.
C150	19A116656P15J0	Ceramic disc: 15 pF ±5%, 500 VDCW, temp coef	C616			L119	19A138298P1	Coil.
thru C152		О РРМ.	C617 C618	19A134730P1 19A134730P2	Electrolytic: 47 uF +100 -10%, 16 VDCW.  Electrolytic: 220 uF +100 -10%, 25 VDCW.	L120	19A702028P2	Coil.
C401 and	19A700219P26	Ceramic: 10 pF ±5%, 100 VDCW, temp coef 0 PPM.	C620	19A700233P5	Ceramic: 470 pF ±20%, 50 VDCW.	L401 and	19B233593P2	Coil, RF: sim to Paul Smith SK-832-1.
C402		_	and C621			L402		
C403	19A700233P7	Ceramic: 1000 pF ±20%, 50 VDCW.	C623	19A700233P5	Ceramic: 470 pF <u>+</u> 20%, 50 VDCW.	L403 L404	19B233593P1 19B233593P2	Coil, RF: sim to Paul Smith SK-832-1.
C404 C405	19A700219P18 19A700235P24	Ceramic: 4.7 pF +5%, 100 VDCW, temp coef 0 PPM.  Ceramic: 82 pF +5%, 50 VDCW.	and C624			L404 L405	19B233593P2 19B233593P1	Coil, RF: sim to Paul Smith SK-832-1.  Coil, RF: sim to Paul Smith SK-832-1.
C405	19A700233P24	Ceramic: 1000 pF ±20%, 50 VDCW.	C625	19A701534P2	Tantalum: 0.22 uF <u>+</u> 20%, 35 VDCW.	L406	19A138400G1	Coil.
and C407					DIODES	L407	19B233593P3	Coil, RF: sim to Paul Smith SK-832-1.
C408	19A700235P16	Ceramic: 18 pF ±5%, 50 VDCW.	D101	19A116052P1	Silicon, hot carrier: Fwd drop .350 volts max.	and L408		
C409 and	19A700233P7	Ceramic: 1000 pF <u>+</u> 20%, 50 VDCW.	D102	19A116052P2	Silicon, hot carrier: Fwd. drop .410 volts max.	L409	19A134729P4	Coil, RF: sim to Paul Smith SK-832-1.
C410			D103	19A115100P2	Silicon; sim to Type 1N459A.	L410	19A138400G1	Coil.
C501	19A700235P22	Ceramic: 56 pF ±5%, 50 VDCW.	D401	19A116052P4	Silicon, hot carrier: Fwd. drop .350 volts max. (Includes D402).	L411	19A136535P1	Coil.
C502 C503	19A700233P5 19A700234P7	Ceramic: 470 pF ±20%, 50 VDCW.  Polyester: 0.01 uF ±10%, 50 VDCW.	D402		(Part of D401).	L412 L413	19J706083P23 19A701768G1	Coil, RF: variable.
thru C505	19870023427	Polyester. V.or ur -10w, 50 vbcw.	D501 and	19A700028P1	Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.	L501	19A134729P4	Coil, RF: sim to Paul Smith SK-832-1.
C506	19A700235P12	Ceramic: 8.2 pF $\pm$ 0.25 pF, 50 VDCW.	D502			L502	19B800691P1	Coil, RF: single pole, wire size No. 24 AWG.
C507	19A700235P15	Ceramic: 15 pF ±5%, 50 VDCW.	D601 thru D605	19A700028P1	Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type iN4148.	L503 and	19A134747P1	Transformer, IF: 455 KHz.
C508	19A700235P20	Ceramic: 39 pF ±5%, 50 VDCW.	D605	19A134738P1	Diode, optoelectronic: red; sim to Siemans	L504		
C509	19A700234P5	Polyester: 4700 pF ±10%, 50 VDCW.			LD41/i1.	L505	19J706029P4	Coil, RF: variable; sim to Paul Smith EF223.
C510	19A701534P4	Tantalum: 1 uF ±20%, 35 VDCW.	D607	19A700028P1	Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.	L506	19A700024P1	Coil, RF: 100 nH ±10%, 0.08 ohms DC res max, 100 v.
C511 C512	19A701534P2 19A701534P4	Tantalum: 0.22 uF <u>+</u> 20%, 35 VDCW.  Tantalum: 1 uF <u>+</u> 20%, 35 VDCW.	D608	19A134354P3	Diode, optoelectronic: Green; sim to Hew. Packard 5082-4955.	L601	19A702322P1	Reactor, (Audio Freq): 75 MHz ±10%; sim to Festinduktivetaten DR 270/5-CL.
thru C514			D609	19A700028P1	Silicon, fast recovery: fwd current 75 mA,	İ		1
C515	19A701534P5	Tantalum: 2.2 uF, <u>+</u> 20%, 35 VDCW.			75 PIV; sim to Type 1N4148.	P101	19A116659P1	
and C516			į		JACKS AND RECEPTACLES	7101	13411003371	5 amps; sim to Molex 09-52-3032.
C517 and	19A700233P3	Ceramic: 220 pF ±10%, 50 VDCW.	J101 and	19A701883P4	Contact, electrical; sim to AMP 86444-1. (Strip Form).	P901	19A116659P15	Connector, printed wiring: 4 contacts rated at 5 amps; sim to Molex 09-52-3042.
C518 C519	19A700233P7	Ceramic: 1000 pF ±20%, 50 VDCW.	J102 J602	19A116659P103	Connector, printed wiring: 4 contacts rated at	L903	19A116659P83	Connector, printed wiring: 7 contacts rated at 5 amps; sim to Molex 09-52-3072 SPECIAL.
C520	19A701534P4	Tantalum: 1 uF ±20%, 35 VDCW.	****	152110007100	5 amps; sim to Molex 09-60-1041.	L912	19A116659P15	Connector, printed wiring: 4 contacts rated at
C521	19A134730P3	Electrolytic: 470 uF +100 -10%, 16 VDCW.	J603	19A700072P30	Connector, printed wiring: 4 contacts rated at 2.5 amps; sim to Molex 22-27-2041.	İ		5 amps; sim to Molex 09-52-3042.
C522	19A700234P4	1Polyester: 3300 pF <u>+</u> 10%, 50 VDCW.						
C523	19A700233P7	Ceramic: 1000 pF <u>+</u> 20%, 50 VDCW.	K601	19A700061P1	Hermetic sealed: 180 to 341 ohms coil res,	Q101 thru	19A134336P1	Silicon, NPN.
C524	19A700002P25	Ceramic disc: 100 pF ±5%, 50 VDCW; temp coef -150 +60 PPM.			8-16.3 VDC; sim to GE 3SAV1760A2, CPClare HFW-1201558, or Potter-Brumfield HCM6160.	Q105		
C525	19A700235P13	Ceramic: 10 pF <u>+</u> 5%, 50 VDCW.				Q106 Q107	19A134697P1 19A700023P1	Silicon, NPN. Silicon, NPN; sim to Type 2N3904.
C526	19A700235P22	Ceramic: 56 pF <u>+</u> 5%, 50 VDCW.	L101	19J706154P10	INDUCTORS RF Coil: sim to Paul Smith SK802-1.	and Q108	152.0002571	bilicon, NFN, bim to Type andbot.
C601	19A700234P5	Polyester: 4700 pF ±10%, 50 VDCW.	thru L103	100.00104110	in corr. Sim to radi bartin bacob ri	Q109	19A700022P1	Silicon, PNP; sim to Type 2N3906.
			L104	19J706085P4	Coil, RF: 0.065 uH ind., ±5%; sim to Paul Smith	1		
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Q401 19A134 Q402 19A116 Q501 19A116 Q501 19A116 Q601 19A116 And 19A100 R101 19A700 R102 19A700 R103 19A700 R104 19A700 R105 3R152F R106 19A700 R107 19A700 R108 19A700 R109 19A700 R110 19A700 R111 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	1116742P1 1134336P1 1116818P1 1116774P1 1134749P1 1700106P39 1700106P77 1700106P93 1700106P55 152P113J	Silicon, NPN.  Silicon, NPN.  N Channel, field effect.  N Channel, field effect.  Silicon, NPN; sim to Type 2N5210.  Silicon, PNP; sim to Type 2N5087.	R505 R506 R507 R508 and R509 R510	19A700019P37 19A700019P48 19A700019P47 19A700019P41 19A700019P33	Deposited carbon: 1K ohms ±5%, 1/4 w.  Deposited carbon: 8.2K ohms ±5%, 1/4 w.  Deposited carbon: 6.8K ohms ±5%, 1/4 w.  Deposited carbon: 2.2K ohms ±5%, 1/4 w.	R629 R630 R631 R632	19A700019P48 19A134753P1 19A700019P29 19A700019P1	Deposited carbon: 8.2K ohms ±5%, 1/4 w.  Variable, carbon film: 47K ohms ±20%, 0.1 w.  Deposited carbon: 220 ohms ±5%, 1/4 w.	Y501A	19B233066G8	NOTE: When reordering give GE Part Number and specify exact frequency needed.  Crystal: freq range 45.455 MHz.
Q402 19A116 Q501 19A116 Q501 19A116 q601 19A116 q602 Q603 19A134 thru Q605 19A700 R102 19A700 R103 19A700 R104 19A700 R105 3R152F R106 19A700 R107 19A700 R108 19A700 R109 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	1116818P1 1116818P1 1116774P1 1134749P1 1700106P39 1700106P77 1700106P93 1700106P55	N Channel, field effect.  N Channel, field effect. Silicon, NPN; sim to Type 2N5210.  Silicon, PNP; sim to Type 2N5087.	R507 R508 and R509 R510	19A700019P47 19A700019P41 19A700019P33	Deposited carbon: 6.8K ohms ±5%, 1/4 w.	R631	19A700019P29	Deposited carbon: 220 ohms ±5%, 1/4 w.	Y501A	19B233066G8	specify exact frequency needed.
Q501 19A116 Q601 19A116 and Q602 Q603 19A134 thru Q605  R101 19A700 R102 19A700 R103 19A700 R104 19A700 R105 3R152F R106 19A700 R107 19A700 R108 19A700 R110 19A700 R111 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	1116818P1 1116774P1 1134749P1 1700106P39 1700106P77 1700106P93 1700106P55	N Channel, field effect.  Silicon, NPN; sim to Type 2N5210.  Silicon, PNP; sim to Type 2N5087.	R508 and R509 R510	19A700019P41	- · ·	1			Y501A	19B233066G8	
Q601 and Q602 Q603 thru Q605 19A134 16A134 19A100 R102 19A700 R104 19A700 R105 19A700 R106 19A700 R107 19A700 R108 19A700 R101 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F R119	1116774P1 1134749P1 1700106P39 1700106P77 1700106P93 1700106P55	Silicon, NPN; sim to Type 2N5210.  Silicon, PNP; sim to Type 2N5087.	and R509 R510 R511	19A700019P33	Deposited carbon: 2.2K ohms ±5%, 1/4 w.	R632	19470001911	1		1002000000	
and Q602 Q603 thru Q605  R101 19A700 R102 19A700 R103 19A700 R104 19A700 R105 3R152F R106 19A700 R107 19A700 R108 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	1134749P1 1700106P39 1700106P77 1700106P93 1700106P55	Silicon, PNP; sim to Type 2N5087.	R509 R510 R511				108.0001071	Deposited carbon: 1 ohms ±5%, 1/4 w.	Y501B	19B233066G9	Crystal: freq range 45.4675 MHz.
Q602 Q603 thru Q605  R101 19A700 R102 19A700 R103 19A700 R104 19A700 R105 3R152F R106 19A700 R107 19A700 R108 19A700 R109 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	1700106P39 1700106P77 1700106P93 1700106P55 152P113J		R511		•	R633	19A700019P40	Deposited carbon: 1.8K ohms ±5%, 1/4 w.	13018	19823300003	Clystal. Hed lange 40.4070 mile.
thru Q805  R101 19A700 R102 19A700 R103 19A700 R104 19A700 R105 3R152F R106 19A700 R107 19A700 R108 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	1700106P39 1700106P77 1700106P93 1700106P55 152P113J		1 1		Deposited carbon: 470 ohms ±5%, 1/4 w.	R634	19A700019P13	Deposited carbon: 10 ohms $\pm 5\%$ , 1/4 w.			
R101 19A700 R102 19A700 R103 19A700 R104 19A700 R105 3R152F R106 19A700 R107 19A700 R108 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	1700106P77 1700106P93 1700106P55 152P113J	Composition: 100 ohms ±5%, 1/4 w.	,,,	19A700019P43	Deposited carbon: 3.3K ohms ±5%, 1/4 w.	R635	19A700019P22	Deposited carbon: 56 ohms $\pm 5\%$ , 1/4 w.	Z501A	19B209613P2	Filter, bandpass: 45.000000 MHz.
R102 19A700 R103 19A700 R104 19A700 R105 3R152F R106 19A700 R107 19A700 R108 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	1700106P77 1700106P93 1700106P55 152P113J	Composition: 100 ohms ±5%, 1/4 w.	R512	19A700019P31	Deposited carbon: 330 ohms +5%, 1/4 w.	R636A	19A700019P30	Deposited carbon: 270 ohms ±5%, 1/4 w.	Z501B	19B209613P3	Filter, bandpass: 45.0125 ref freq, 13 kHz
R102 19A700 R103 19A700 R104 19A700 R105 3R152F R106 19A700 R107 19A700 R108 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	1700106P77 1700106P93 1700106P55 152P113J		and R513		<u> </u>	R636B	19A700019P25	Deposited carbon: 100 ohms ±5%, 1/4 w.	7500	10170017171	bandwidth.
R103 19A700 R104 19A700 R105 3R152F R106 19A700 R107 19A700 R108 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	A700106P93 A700106P55 L52P113J	Composition: 3 9K ohms +5% 1/4 m	R514	19A700019P39	Deposited carbon: 1.5K ohms ±5%, 1/4 w.	R636C	19A700019P21	Deposited carbon: 47 ohms ±5%, 1/4 w.	Z502	19A702171P1	Filter, bandpass: $455 \pm 1.5$ kHz; sim to Murata CFU455D2.
R104 19A700 R105 3R152F R106 19A700 R107 19A700 R108 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	A700106P55 152P113J	Composition: 5:5k Ohms -5%, 1/4 w.	R515	19A700019P50	Deposited carbon: 12K ohms ±5%, 1/4 w.	R636D	19A700019P17	Deposited carbon: 22 ohms ±5%, 1/4 w.			
R105 3R152F R106 19A700 R107 19A700 R108 19A700 R109 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	152P113J	Composition: 18K ohms ±5%, 1/4 w.	R516	19A700019P35	Deposited carbon: 680 ohms ±5%, 1/4 w.	R636E	19A700019P11	Deposited carbon: 6.8 ohms ±5%, 1/4 w.	[		MISCELLANEOUS
R106 19A700 R107 19A700 R108 19A700 R109 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F		Composition: 470 ohms ±5%, 1/4 w.	R517	19A700019P47	Deposited carbon: 6.8K ohms +5%, 1/4 w.	R637	19A700019P35	Deposited carbon: 680 ohms ±5%, 1/4 w.		19B800576P1	Shield. (Used with Q106).
R107 19A700 R108 19A700 R109 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	4700106P63	Composition: 11K ohms ±5%, 1/4 w.	R518	19A700019P48	Deposited carbon: 8.2K ohms +5%, 1/4 w.	R638	19A700018P1	Deposited carbon: 1 ohm ±5%, 1/3 w.		19B232901P1	Support. (Secures printed board - Quantity 3).
R107 19A700 R108 19A700 R109 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F		Composition: 1K ohms ±5%, 1/4 w.	R519	19A700019P39	Deposited carbon: 0.2k Ohms ±5%, 1/4 w.	R639	19A700019P25	Deposited carbon: 100 ohms ±5%, 1/4 w.		19A700069P1	Can. (Used with L409 & L501).
R108 19A700 R109 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	A700106P45	Composition: 180 ohms +5%, 1/4 w.	R520	19A700019P39	<del>-</del>	R640A	19A700019P13	Deposited carbon: 10 ohms ±5%, 1/4 w.		19A701544P1	Can. (Used with L502 & L505).
R109 19A700 R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	A700106P15	Composition: 10 ohms ±5%, 1/4 w.	R521		Deposited carbon: 10K ohms ±5%, 1/4 w.	R640B	19A700019P41	Deposited carbon: 2.2K ohms ±5%, 1/4 w.		19D429946P2	Casting. (Located at L401-L407).
R110 19A700 R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	A700106P39	Composition: 100 ohms ±5%, 1/4 w.	R521	19B800784P209	Variable: 25K ohms ±20%, 1/2 w; sim to Murata Type RVG0911V328.	R640C	19A700019P57	Deposited carbon: 47K ohms ±5%, 1/4 w.		19B850619G1	Casting. (Located at L101-L103).
R111 19A700 R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	A700106P63	Composition: 1K ohms ±5%, 1/4 w.	R522	19A700019P49	Deposited carbon: 10K ohms $\pm 5\%$ , 1/4 w.	R642	19A700019P37	Deposited carbon: 1K ohms ±5%, 1/4 w.		19A700115P3	Insulator, plate. (Used with Q110 & U602).
R112 3R152F R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F	A700106P81	Composition: 5.6K ohms ±5%, 1/4 w.	R523	19A700019P43	Deposited carbon: 3.3K ohms $\pm 5\%$ , 1/4 w.	R644	19A700019P38	Deposited carbon: 1.2K ohms ±5%, 1/4 w.		19A700068P1	Insulator, bushing. (Used with Q110 & U602).
R114 19A700 R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F		Composition: 510 ohms ±5%, 1/4 w.	R524	19A700019P56	Deposited carbon: 39K ohms ±5%, 1/4 w.		19A700019P38	Deposited carbon: 10K ohms ±5%, 1/4 w.		19B233285P1	Ground spring. (Located at C404).
R115 19A700 R116 3R152F R117 19A700 R118 3R152F R119 3R152F		-	and R525			R645		Deposited carbon: 1.2K ohms ±5%, 1/4 w.		19C850671P1	Ground strap. (Located near K601 on printed board).
R116 3R152F R117 19A700 R118 3R152F R119 3R152F		Composition: 100 ohms ±5%, 1/4 w.	R526	19A700019P9	Deposited carbon: 4.7 ohms ±5%, 1/4 w.	R646	19A700019P38	l -		19A701874P1	Tab. (Located under W102 & W104 solder side of
R117 19A700 R118 3R152F R119 3R152F	A700106P73	Composition: 2.7K ohms ±5%, 1/4 w.	R528	19A700019P36	Deposited carbon; 820 ohms ±5%, 1/4 w.	R647	19A700019P54	Deposited carbon: 27K ohms ±5%, 1/4 w.	ŀ	19870187491	board).
R118 3R152F R119 3R152F	152P511J	Composition: 510 ohms ±5%, 1/4 w.	R601	19A700019P57	Deposited carbon: 47K ohms ±5%, 1/4 w.	R648	19A700019P37	Deposited carbon: 1K ohms ±5%, 1/4 w.	1	19C328587P1	Knob. (Used with S601 & S602).
R119 3R152F	A700106P23	Composition: 22 ohms ±5%, 1/4 w.	R602	19A700019P53	Deposited carbon: 22K ohms ±5%, 1/4 w.	l .		SWITCHES	ı	19D429826P1	Knob. (Used with R630).
1 1	152P622J	Composition: 6200 ohms ±5%, 1/4 w.	R603	19A700019P31	Deposited carbon: 330 ohms ±5%, 1/4 w.	8601	19B800563P1	Push: DPDT, 1 station, alternate action; sim to	l	19A701743P1	Pad. (Located behind S601 & S602 knobs).
P120 104700	152P511J	Composition: 510 ohms ±5%, 1/4 w.	R604	19A700019P52	Deposited carbon: 18K ohms ±5%, 1/4 w.	and 8602	ļ	IEEE/SCHADOW 51281 (F2UEE).	ı	19A138451P1	Tuning slug. (Used with L101-L103 & L107-L109).
1	A700106P47	Composition: 220 ohms ±5%, 1/4 w.	R605	19A700019P49	Deposited carbon: 10K ohms ±5%, 1/4 w.					19A701886P1	Spring. (Used with L107-L109, L401-L407, L409,
R121 19A700	A700106P69	Composition: 1.8K ohms ±5%, 1/4 w.	R606	19A700019P66	Deposited carbon: 0.27M ohms ±5%, 1/4 w.	1			l		L412 & L501).
R122 19A700	A700113P23	Composition: 22 ohms ±5%, 1/2 w.	R607	19B800784P208	Variable: 10K ohms ±20%, 1/2 w; sim to Murata	TP101	19A700152P1	Contact.	1	NP280878P1	Nameplate. (POWER).
R123 19A700	A700106P63	Composition: 1K ohms ±5%, 1/4 w.	1 1001	1300001041200	Type RVG0911V328.	TP103	19A700152P1	Contact.	· I	NP280878P2	Namplate. (SQUELCH).
R124 19A700	A700106P15	Composition: 10 ohms ±5%, 1/4 w.	R608	19A700019P47	Deposited carbon: 6.8K ohms $\pm 5\%$ , 1/4 w.	TP104	19A700152P1	Contact. (Quantity 2).	l l	19A701785P5	Contact, electrical. (Located at A102 - Quantity 6).
R125 19A700	A700106P29	Composition: 39 ohms ±5%, 1/4 w.	R609	19A701828P2	Thermistor: 470 pF <u>+</u> 20%; sim to Phillips 2322-642-61471.	TP401	19A700152P1	Contact. (Quantity 2).	1	19A134753P5	Machine screw. (Secures R630 knob).
R126 19A700	A700016P3	Variable, cermet: 4.7K ohms $\pm 10\%$ , 1/2 w.	Para	104700010040	ļ	TP501	19A700152P1	Contact. (Quantity 2).	1	19J706076P1	Washer, spring. (Secures R630 knob)
R127 19A700	A700106P71	Composition: 2.2K ohms ±5%, 1/4 w.	R610	19A700019P48	Deposited carbon: 8.2K ohms ±5%, 1/4 w.			INTEGRATED CIRCUITS		19A134753P2	Washer. (Secures R630 knob).
R128 19A700	A700106P63	Composition: 1K ohms ±5%, 1/4 w.	R611	19A700019P26	Deposited carbon: 120 ohms ±5%, 1/4 w.		10000000001	Mixer, balanced.	İ	19A702364P208	Machine screw: TORX®Drive, M2.5 - 0.45 x 8.
R129 19A700	A700106P83	Composition: $6.8K$ ohms $\pm 5\%$ , $1/4$ w.	R612	19A700019P33	Deposited carbon: 470 ohms ±5%, 1/4 w.	U101	19B209680P1	Linear, Dual Differential Amplifier, 14 Pin Dip.	1	101110110111100	(Secures Q110, U601 & U602).
R130 19A700	A700106P69	Composition: 1.8K ohms ±5%, 1/4 w.	R613	19A700019P36	Deposited carbon: 820 ohms ±5%, 1/4 w.	U501	19A134759P1		i	19A700034P3	Hex nut, metric: M2.5 x 0.45. (Secures Q110, U601 & U602).
R131 19A700	A700106P55	Composition: 470 ohms ±5%, 1/4 w.	R614	19A700019P44	Deposited carbon: 3.9K ohms <u>+</u> 5%, 1/4 w.	U502	19A134766P1	Linear, Outline For 16-Pin Dip case.		19A700032P3	
R132 19A700	A700106P47	Composition: 220 ohms ±5%, 1/4 w.	R615	19A700019P57	Deposited carbon: 47K ohms ±5%, 1/4 w.	U601	19A134769P2	Linear: sim to TDA 2002.		194700032P3	Lockwasher, tooth, steel, metric: 2.5. (Secures Q110, U601 & U602).
R133 19A700	A700106P57	Composition: 560 ohms ±5%, 1/4 w.	R616	19A700019P49	Deposited carbon: 10K ohms ±5%, 1/4 w.	U602	19A138414G1	Regulator: 8.5 V.		19A701312P3	Flatwasher, metric: No. 2.5MM. (Secures Q110 &
R401 19A700	A700106P65	Composition: 1.2K ohms ±5%, 1/4 w.	R617	19A700019P68	Deposited carbon: 0.39M ohms ±5%, 1/4 w.		1			10.70000	Voobles seems many not to the seems of the s
R402 19A700	A700106P75	Composition: 3.3K ohms ±5%, 1/4 w.	R618	19A700019P50	Deposited carbon: 12K ohms $\pm 5\%$ , 1/4 w.	W101		Microstrip inductor. (Part of printed board	1	19A702364P106	Machine screw: TORX®Drive, No. M2 - 0.4 x 6. (Secures printed board).
R403 19A700	A700106P63	Composition: 1K ohms ±5%, 1/4 w.	R619 and	19A700019P54	Deposited carbon: 27K ohms $\pm 5\%$ , 1/4 w.	thru W108		19D900231P1).		19A138451P2	Spring. (Used with L401-L405, L407, & L408).
1 1	A700106P39	Composition: 100 ohms ±5%, 1/4 w.	R620			W401	1	Microstrip inductor. (Part of printed board			
1 1	A700019P56	Deposited carbon: 39K ohms ±5%, 1/4 w.	R621	19A700019P40	Deposited carbon: 1.8K ohms $\pm 5\%$ , 1/4 w.	thru W408		19D900231P1).	1	1	
1	A700019P57	Deposited carbon: 47K ohms +5%, 1/4 w.	R622	19A700019P31	Deposited carbon: 330 ohms ±5%, 1/4 w.	W601		Microstrip inductor. (Part of printed board	1		
1 1	A700019P29	Deposited carbon: 220 ohms ±5%, 1/4 w.	R623	19A700019P47	Deposited carbon: 6.8K ohms $\pm 5\%$ , 1/4 w.			19D900231P1).	1		
1	A700019P31	Deposited carbon: 330 ohms +5%, 1/4 w.	R624	19A700019P58	Deposited carbon: 56K ohms ±5%, 1/4 w.		I				
1	A700019P53	Deposited carbon: 22K ohms +5%, 1/4 w.	R625 and	19A700019P37	Deposited carbon: 1K ohms $\pm 5\%$ , 1/4 w.	X501	1	Socket. Includes:		1	
1 1	A700019P54	Deposited carbon: 27K ohms ±5%, 1/4 w.	R626				19A702742P1	Crystal socket. (Quantity 2).		1	
and R503			R627A	19A700019P29	Deposited carbon: 220 ohms ±5%, 1/4 w.		19B233285P1	Ground spring.	1		
1			R627B	19A700019P27	Deposited carbon: 150 ohms $\pm 5\%$ , 1/4 w.		100200001		1		
	1		and R628A						1		
			R628B	19A700019P28	Deposited carbon: 180 ohms ±5%, 1/4 w.						
					1		I	1	1	1	
						i	I	1			

# ☐ LBI31004

# PARTS LIST

800 MHz TRANSMITTER/RECEIVER 19D90074265 CENTURA CORONA 19D90074266 CLASSIC

SYMBOL	GE PART NO.	DESCRIPTION
A2		TRANSMITTER/RECEIVER BOARD 199900232G5 (STD) REV E 199900232G6 (K5) REV E
A102		LOW PASS FILTER BOARD 190850655G1
L3	19A701782P1	Coil.
L5	19A701782P1	Coil.
C101	19A700219P30	Ceramic: 12 pF ±5%, 100 VDCW, temp coef 0 PPM.
C102	19A700219P48	Ceramic: 36 pF ±5%, 100 VDCW, temp coef 0 PPM.
C103	19A700234P7	Polyester: 0.01 uF ±10%, 50 VDCW.
C104	19A701534P5	Tantalum: 2.2 uF, ±20%, 35 VDCW.
C105	19A116192P1	Ceramic: 0.01 uF $\pm$ 20%, 50 VDCW; sim to Erie 812
C106	19A116192P2	SPECIAL.  Ceramic: 470 pF ±20%, 50 VDCW; sim to Erie
		811-A050-W5R-471M.
C107	19A700219P10	Ceramic: 2.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C108	19A700219P24	Ceramic: 8.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C109	19A116192P1	Ceramic: 0.01 uF ±20%, 50 VDCW; sim to Erie 8121 SPECIAL.
C110	19A700219P48	Ceramic: 36 pF ±5%, 100 VDCW, temp coef 0 PPM.
C112	19A700219P10	Ceramic: 2.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C113	19A116192P2	Ceramic: 470 pF ±20%, 50 VDCW; sim to Erie 811-A050-W5R-471M.
C114	19A700219P33	Ceramic: 15 pF ±5%, 100 VDCW, temp coef 0 PPM.
C115	19A700219P48	Ceramic: 36 pF ±5%, 100 VDCW, temp coef 0 PPM.
C116	19A700219P14	Ceramic: 3.3 pF ±5%, 100 VDCW, temp coef 0 PPM.
C117	19A116192P1	Ceramic: 0.01 uF ±20%, 50 VDCW; sim to Erie 8123 SPECIAL.
C118	19A700219P33	Ceramic: 15 pF ±5%, 100 VDCW, temp coef 0 PPM.
C119	19A700219P24	Ceramic: 8.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C120	19A700219P10	Ceramic: 2.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C121	19A700219P14	Ceramic: 3.3 pF ±5%, 100 VDCW, temp coef 0 PPM.
C122	19A700219P33	Ceramic: 15 pF ±5%, 100 VDCW, temp coef 0 PPM.
C123	19A701534P5	Tantalum: 2.2 uF, ±20%, 35 VDCW.
C124	19A700234P7	Polyester: 0.01 uF ±10%, 50 VDCW.
C125	19A700008P2	Variable: 2.28 to 14.13 pF; sim to EF Johnson 187-0109-005.
C126	19A700219P14	Ceramic: 3.3 pF ±5%, 100 VDCW, temp coef 0 PPM.
C127	19A700008P3	Variable, air: 1.56 to 4.86 pF; sim to EF Johnson 187-0103-005.
C128	19A116192P1	Ceramic: 0.01 uF ±20%, 50 VDCW; sim to Erie 8121 SPECIAL.
C129	19A116192P2	Ceramic: 470 pF ±20%, 50 VDCW; sim to Erie 811-A050-W5R-471M.
C130	19A700219P33	Ceramic: 15 pF ±5%, 100 VDCW, temp coef 0 PPM.
C131	19A700219P26	Ceramic: 10 pF ±5%, 100 VDCW, temp coef 0 PPM.
C132	19A700219P24	Ceramic: 8.2 pF ±5%, 100 VDCW, temp coef 0 PPM.
C133	19A700008P2	Variable: 2.28 to 14.13 pF; sim to EF Johnson 187-0109-005.
C134	19A700008P3	Variable, air: 1.56 to 4.86 pF; sim to EF Johnson 187-0103-005.

	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	, 
	C135	19A700219P33	Ceramic: 15 pF ±5%, 100 VDCW, temp coef 0 PPM.	C602	19A700234P6	Polyester: 6800 pF ±10%, 50 VDCW.	L105	19J706085P8	Coil, RF: 0.110 uH ind., $\pm 5\%$ ; sim to Paul Smith LM-2.	ĺ
	C136	19A116655P14	Ceramic disc: 470 pF ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C603	19A700234P11 19A701534P6	Polyester: 0.047 uF $\pm$ 10%, 50 VDCW. Tantalum: 4.7 uF $\pm$ 20%, 35 VDCW.	L106	19B209420P101	Coil, RF: .10 uH $\pm$ 10%, 0.8 ohms DC res max; sim to Jeffers $\pm$ 416-1K.	i
	C137 and	19A701534P7	Tantalum: 10 uF ±20%, 16 VDCW.	C605	19A134730P1	Electrolytic: 47 uF +100 -10%, 16 VDCW.	L107 thru	19B233593P4	Coil, RF: sim to Paul Smith SK-832-1.	l
_	C138 C139	19A701225P1	Electrolytic: 15 uF -10 +75%, 25 VDCW; sim to	C606	19A701534P4	Tantalum: 1 uF ±20%, 35 VDCW.	L109 L110	19A701524P1	Coil.	l
	C140	19A700006P32	Sprague $501D156$ - $GO25BB1C$ .  Mica: 82 pF $\pm$ 5%, 100 VDCW; sim to Underwood	C607	19A700234P8	Polyester: .015 uF ±10%, 50 VDCW; sim to NISSEI AMXV or AMZV.	L111	19A701524P1	Coil.	ĺ
			3HS0020.	C608 and	19A700234P13	Polyester: 0.1 uF ±10%, 50 VDCW.	L112	19A701524P2	Coil.	ĺ
l	C141 C142	19A701534P1 19A700004P2	Tantalum: 0.1 uF ±20%, 35 VDCW.	C607 C610	19A701534P7	Tantalum: 10 uF ±20%, 16 VDCW.	L113	19A701524P3	Coil.	
Ì	C142	19A116192P2	Metallized polyester: 0.1 uF ±10%, 63 VDCW.  Ceramic: 470 pF ±20%, 50 VDCW; sim to Erie	C611	19A700234P13	Polyester: 0.1 uF ±10%, 50 VDCW.	L114	19A701524P1	Coil.	
			811-A050-W5R-471M.	C612	19A702250P113	Polyester: 0.1 uF ±10%, 50 VDCW.	L115	19B209420P101	Coil, RF: .10 uH ±10%, 0.8 ohms DC res max; sim to Jeffers 4416-1K.	
	C144 thru C146	19A143565P8	Ceramic: 0.1 uF <u>+</u> 10%, 50 VDCW.	C613	19A700004P6	Metallized Polyester: 0.47 ±10%, 63 VDCW.	L116	19A701524P4	Coil.	
	C147	19A701534P4	Tantalum: 1 uF ±20%, 35 VDCW.	C614	19A134730P2	Electrolytic: 220 uF +100 -10%, 25 VDCW.	L117 L118	19A701524P1 19B209420P101	Coil. RF: .10 uH ±10%, 0.8 ohms DC res max; sim	ĺ
	thru C149		- 1	C615 and C616	19A700234P12	Polyester: 0.068 uF <u>+</u> 10%, 50 VDCW.	LIIO	1982094209101	to Jeffers 4416-1K.	
-	C150 thru	19A116656P15J0	Ceramic disc: 15 pF ±5%, 500 VDCW, temp coef 0 PPM.	C617	19A134730P1	Electrolytic: 47 uF +100 -10%, 16 VDCW.	L119	19A138298P1	Coil.	
.	C152		· · · · ·	C618	19A134730P2	Electrolytic: 220 uF +100 -10%, 25 VDCW.	L120	19A702028P2	Coil.	ŀ
	C401 and C402	19A700219P26	Ceramic: 10 pF ±5%, 100 VDCW, temp coef 0 PPM.	C620 and C621	19A700233P5	Ceramic: 470 pF <u>±</u> 20%, 50 VDCW.	L401 and L402	19B233593P2	Coil, RF: sim to Paul Smith SK-832-1.	
	C403	19A700233P7	Ceramic: 1000 pF <u>+</u> 20%, 50 VDCW.	C623	19A700233P5	Ceramic: 470 pF ±20%, 50 VDCW.	L403	19B233593P1	Coil, RF: sim to Paul Smith SK-832-1.	
121	C404	19A700219P18	Ceramic: 4.7 pF ±5%, 100 VDCW, temp coef 0 PPM.	and C624			L404	19B233593P2 19B233593P1	Coil, RF: sim to Paul Smith SK-832-1.  Coil, RF: sim to Paul Smith SK-832-1.	
	C405	19A700235P24	Ceramic: 82 pF ±5%, 50 VDCW.	C625	19A701534P2	Tantalum: 0.22 uF ±20%, 35 VDCW.	L405 L406	19B233593P1 19A138400G1	Coil.	
	C406 and C407	19A700233P7	Ceramic: 1000 pF <u>+</u> 20%, 50 VDCW.				L407	19B233593P3	Coil, RF: sim to Paul Smith SK-832-1.	
м.	C408	19A700235P16	Ceramic: 18 pF ±5%, 50 VDCW.	D101	19A116052P1	Silicon, hot carrier: Fwd drop .350 volts max.	and L408			
121	C409	19A700233P7	Ceramic: 1000 pF ±20%, 50 VDCW.	D102	19A116052P2	Silicon, hot carrier: Fwd. drop .410 volts max.	L409	19A134729P4	Coil, RF: sim to Paul Smith SK-832-1.	1
	C410			D103	19A115100P2	Silicon; sim to Type 1N459A.	L410	19A138400G1	Coil.	
	C501	19A700235P22	Ceramic: 56 pF <u>+</u> 5%, 50 VDCW.	D401	19A116052P4	Silicon, hot carrier: Fwd. drop .350 volts max. (Includes D402).	L411 L412	19A136535P1 19J706083P23	Coil. Coil, RF: variable.	
•	C502 C503	19A700233P5 19A700234P7	Ceramic: 470 pF ±20%, 50 VDCW.	D402		(Part of D401).	L413	19A701768G1	Coil.	
	thru C505	19870023497	Polyester: 0.01 uF ±10%, 50 VDCW.	D501 and	19A700028P1	Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.	L501	19A134729P4	Coil, RF: sim to Paul Smith SK-832-1.	
٠	C506	19A700235P12	Ceramic: 8.2 pF <u>+</u> 0.25 pF, 50 VDCW.	D502 D601	19A700028P1	Silicon, fast recovery: fwd current 75 mA,	L502	19B800691P1	Coil, RF: single pole, wire size No. 24 AWG.	
u.	C507	19A700235P15	Ceramic: 15 pF <u>+</u> 5%, 50 VDCW.	thru D605	19470002871	75 PIV; sim to Type 1N4148.	L503 and	19A134747P1	Transformer, IF: 455 KHz.	
121	C508	19A700235P20	Ceramic: 39 pF ±5%, 50 VDCW.	D606	19A134738P1	Diode, optoelectronic: red; sim to Siemans	L504 L505	19J706029P4	Coil. RF: variable: sim to Paul Smith EF223.	
	C509	19A700234P5	Polyester: 4700 pF ±10%, 50 VDCW.	D607	19A700028P1	LD41/11. Silicon, fast recovery: fwd current 75 mA,	L505	19A700024P1	Coil. RF: 100 nH +10%, 0.08 ohms DC res max,	l
и.	C510 C511	19A701534P4 19A701534P2	Tantalum: 1 uF ±20%, 35 VDCW.  Tantalum: 0.22 uF ±20%, 35 VDCW.	Dec 7	19470002871	75 PIV; sim to Type 1N4148.	ŀ	1	100 v.	l
м.	C512	19A701534P4	Tantalum: 1 uF ±20%, 35 VDCW.	D608	19A134354P3	Diode, optoelectronic: Green; sim to Hew. Packard 5082-4955.	L601	19A702322P1	Reactor, (Audio Freq): 75 MHz ±10%; sim to Festinduktivetaten DR 270/5-CL.	
w.	thru C514	1		D609	19A700028P1	Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.				l
.	C515 and C516	19A701534P5	Tantalum: 2.2 uF, ±20%, 35 VDCW.	<u> </u>		JACKS AND RECEPTACLES	P101	19A116659P1	Connector, printed wiring: 3 contacts rated at 5 amps; sim to Molex 09-52-3032.	
	C517 and	19A700233P3	Ceramic: 220 pF ±10%, 50 VDCW.	J101 and J102	19A701883P4	Contact, electrical; sim to AMP 86444-1. (Strip Form).	P901	19A116659P15	Connector, printed wiring: 4 contacts rated at 5 amps; sim to Molex 09-52-3042.	
	C518 C519	19A700233P7	Ceramic: 1000 pF +20%, 50 VDCW.	J602	19A116659P103	Connector, printed wiring: 4 contacts rated at	L903	19A116659P83	Connector, printed wiring: 7 contacts rated at 5 amps; sim to Molex 09-52-3072 SPECIAL.	1
м.	C520	19A701534P4	Tantalum: 1 uF ±20%, 35 VDCW.	J603	194700072P30	5 amps; sim to Molex 09-60-1041.  Connector, printed wiring: 4 contacts rated at	L912	19A116659P15	Connector, printed wiring: 4 contacts rated at 5 amps; sim to Molex 09-52-3042.	
	C521	19A134730P3	Electrolytic: 470 uF +100 -10%, 16 VDCW.	3003	158,000,2200	2.5 amps; sim to Molex 22-27-2041.				
121	C522	19A700234P4	1Polyester: 3300 pF ±10%, 50 VDCW.			RELAYS	Q101	19A134336P1		
	C523	19A700233P7	Ceramic: 1000 pF ±20%, 50 VDCW.	K601	19A700061P1	Hermetic sealed: 180 to 341 ohms coil res, 8-16.3 VDC; sim to GE 38AV1760A2, CPClare	thru Q105	19413433071	Silicon, New.	İ
.	C524	19A700002P25	Ceramic disc: 100 pF ±5%, 50 VDCW; temp coef -150 +60 PPM.			HPW-1201558, or Potter-Brumfield HCM6160.	Q106	19A134697P1	Silicon, NPN.	
.	C525	19A700235P13	Ceramic: 10 pF <u>+</u> 5%, 50 VDCW.	İ			Q107 and	19A700023P1	Silicon, NPN; sim to Type 2N3904.	1
и.	C526 C601	19A700235P22 19A700234P5	Ceramic: 56 pF ±5%, 50 VDCW.	L101 thru	19J706154P10	RF Coil: sim to Paul Smith SK802-1.	Q108			
3	C601	19870023425	Polyester: 4700 pF ±10%, 50 VDCW.	L103		_	Q109	19A700022P1	Silicon, PNP; sim to Type 2N3906.	
				L104	19J706085P4	Coil, RF: 0.065 uH ind., ±5%; sim to Paul Smith LM-2.				
	1									
	1	1		1						1

LB131004

Column	SYMBOL GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
Column   C	Q110 19A116742P1	Silicon, NPN.	R505	19A700019P37	Deposited carbon: 1K ohms ±5%, 1/4 w.	R629	19A700019P48	Deposited carbon: 8.2K ohms ±5%, 1/4 w.			MEMBADIE
March   Marc	Q401 19A134336P1	Silicon, NPN.	R506	19A700019P48	Deposited carbon: 8.2K ohms $\pm 5\%$ , 1/4 w.	R630	19A134753P1	Variable, carbon film: 47K ohms <u>+</u> 20%, 0.1 w.	7501	10020061303	
Description   Control	Q402 19A116818P1	N Channel, field effect.	R507	19A700019P47	Deposited carbon: 6.8K ohms ±5%, 1/4 w.	R631	19A700019P29	Deposited carbon: 220 ohms $\pm 5\%$ , 1/4 w.	2301	19820901373	
Martine   Mart	Q501 19A116818P1	N Channel, field effect.		19A700019P41	Deposited carbon: 2.2K ohms ±5%, 1/4 w.	R632	19A700019P1	Deposited carbon: 1 ohms ±5%, 1/4 w.	Z502	19A702171P1	Filter, bandpass: 455 ±1.5 kHz; sim to Murata
March   Marc		Silicon, NPN; sim to Type 2N5210.				R633	19A700019P40	Deposited carbon: 1.8K ohms ±5%, 1/4 w.			0.0.0002.
Column   C			R510	19A700019P33	Deposited carbon: 470 ohms ±5%, 1/4 w.	R634	19A700019P13	Deposited carbon: 10 ohms ±5%, 1/4 w.			
100   100	thru	Silicon, PNP; sim to Type 2N5087.	R511	19A700019P43	Deposited carbon: 3.3K ohms ±5%, 1/4 w.	R635	19A700019P22	Deposited carbon: 56 ohms <u>+</u> 5%, 1/4 w.	U102	19A143904P2	RF Amplifier.
\$1000   \$10000   \$10000   \$10000   \$10000   \$10000   \$10000   \$10000   \$10000   \$10000   \$10000   \$10000   \$	1 1		and	19A700019P31	Deposited carbon: 330 ohms ±5%, 1/4 w.	R636A	19A700019P30	Deposited carbon: 270 ohms $\pm 5\%$ , 1/4 w.			
\$1,000   \$						R636B	19A700019P25	Deposited carbon: 100 ohms ±5%, 1/4 w.			MISCELLANEOUS
1975   1976		- · · · ·	1		= '	R636C		Deposited carbon: 47 ohms ±5%, 1/4 w.	1	19A702364P408	Machine screw: TORX®Drive, M3.5 - 0.6 x 8. (Secures U102).
10.00000000000000000000000000000000000	1 1	- · ·	1		_	1		i -	ł	19A700032P6	Lockwasher, internal tooth: No. 3.5MM. (Secures
100   100	1 1	- ' '	1 1		- · ·	1		·	1		,
1000   2000000000   2000000000   200000000	1 1		1		<u> </u>			- I			
Description   Comparison   Control of Control   Control of Control   Control of Control   Cont	1 1 1	-	1 1		- · ·				1	1947023812508	Screw, thd. form: No. 3.5 - 0.6 x 8. (Secures A2 - Quantity 8).
10.00   10.000   10.0000   10.000000   10.000000   10.00000   10.00000   10.000000   10.000000   10.000000   10.000000   10.000000   10.000000   10.000000   10.000000   10.000000   10.0000000   10.0000000   10.0000000   10.0000000   10.0000000   10.00000000   10.000000000   10.000000000   10.000000000   10.0000000000		<del>-</del> · ·	1 1		_	1		-		19A702381P525	Screw, thd. form: No. M3.5 - 0.6 x 25. (Secures
Composition   Composition	1	_	1 1		_	1		-		10000057671	
1.00   1.00	i	_	n521	1980001047209		1		i -			
1.00   1.00		<del>-</del>	R522	19A700019P49	Deposited carbon: 10K ohms ±5%, 1/4 w.	1		- · ·		1	Support. (Secures printed board - Quantity 3).
131-00-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1	1 1		R523	19A700019P43	Deposited carbon: 3.3K ohms $\pm 5\%$ , 1/4 w.	1		l		1	
1310   3870000700   30% comparison   3	1 1	_		19A700019P56	Deposited carbon: 39K ohms ±5%, 1/4 w.			l			
Page   Page	1 1	- · · ·								1	·
Description   Description	1	<u>-</u>	R526	19A700019P9	Deposited carbon: 4.7 ohms $\pm 5\%$ , 1/4 w.	OFON	198700019737	Deposited carbon. In online 10%, 1/4 w.		<b>{</b>	Insulator, plate. (Used with Q110 & U602).
\$10   \$10,000   \$10,000   \$1			R528	19A700019P36	Deposited carbon: 820 ohms $\pm 5\%$ , 1/4 w.			SWITCHES			Insulator, bushing. (Used with Q110 & U602).
10.00   30.0000000000   30.00000000000   30.0000000000	1 1	<u>-</u> · · ·	R601	19A700019P57	Deposited carbon: 47K ohms ±5%, 1/4 w.		19B800563P1	Push: DPDT, 1 station, alternate action; sim to IEEE/SCHADOW 51281 (F2UEE).		1	
1819   38132001101   200 onle 55, 1/4 v.   1600   14270011972   1620 onle 55, 1/4 v.   1600   14270011972   1620 onle 55, 1/4 v.   1600   14270011972   1627001101   200 onle 55, 1/4 v.   1600   14270011972   1627001101   1620 onle 55, 1/4 v.   1600   14270011972   1627001101   1620 onle 55, 1/4 v.   1600   14270011972   1627001101   162700	1 1	<del>-</del> · · ·		19A700019P53	<del>-</del>			1222/001112011 (12022)		1	Ground strap. (Located near K601 on printed
1879   1879					Deposited carbon: 330 ohms ±5%, 1/4 w.						
Accordance   Comparation   C	R120 19A700106P47	Composition: 220 ohms ±5%, 1/4 w.			<del>-</del> · ·	TP101	19A700152P1	i i		19A701874P1	Tab. (Located under W102 & W104 solder side of board).
## 1980/07/1999   198	R121 19A700106P69	Composition: 1.8K ohms <u>+</u> 5%, 1/4 w.			<del>-</del> · ·	TP103		i		19C328587P1	Knob. (Used with S601 & S602).
## 132   19470019995   Composition: 18 chas 155, 1/4 v.   500   19470019995   Composition: 19 chas 155, 1/4 v.   500   1947001999   Composition: 20 chas 155, 1/4 v.   500   1947001999   Composition: 20 chas 155, 1/4 v.   500   1947001999   Composition: 2.0 chas 155, 1/4 v.   500   1947	R122 19A700113P23	Composition: 22 ohms ±5%, 1/2 w.	1		<del>-</del> ' ' '	TP104	19A700152P1	Contact. (Quantity 2).		19D429826P1	Knob. (Used with R630).
### 13470010879   Composition: 30 ohme 15, 1/4 v.   200-20-20-20-21   19470018870   19470018870   19470018870   19470018870   19470018870   19470018870   1947001	R123 19A700106P63	Composition: 1K ohms ±5%, 1/4 w.	R607	198800784P208	Variable: 10K ohms ±20%, 1/2 w; sim to Murata Type RVG0911V328.	TP401	19A700152P1	Contact. (Quantity 2).		19A701743P1	Pad. (Located behind S601 & S602 knobs).
### 19470019979   Variable, carmet: 4.7% chms 105, 1/2 v.   8810   1947001998   Deposited carbon: 5.2% chms 105, 1/4 v.   8811   1947001998   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001998   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001998   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001998   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001998   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001998   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001998   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001998   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001998   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001998   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001998   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   8811   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   1947001999   Deposited carbon: 1.2% chms 105, 1/4 v.   1947001999   Deposited carbon: 1.2% c	R124 19A700106P15	Composition: 10 ohms ±5%, 1/4 w.	R608	19A700019P47	Deposited carbon: 6.8K ohms ±5%, 1/4 w.	TP501	19A700152P1	Contact. (Quantity 2).		19A138451P1	Tuning slug. (Used with L101-L103 & L107-L109).
R286   19470010879   R129   R129	R125 19A700106P29	Composition: 39 ohms ±5%, 1/4 w.	R609	19A701828P2				INTEGRATED GYDGUYTG		19A701886P1	Spring. (Used with L107-L109, L401-L407, L409,
134700106973	R126 19A700016P3	Variable, cermet: 4.7K ohms ±10%, 1/2 w.	R610	194700019P48		11101	10020069001			NP280878P1	·
8123   194700108953   Composition: 1K chms 254, 1/4 v.   19470018953   19470018953   19470018954   19470018954   19470018954   19470018954   19470018954   19470018955   19470018956	R127 19A700106P71	Composition: 2.2K ohms ±5%, 1/4 w.	1		_	1				1	Contact, electrical. (Located at A102 - Quantity
1829   18470016983   136   18470016983   136   18470016983   185   18470016983   185   18470016983   185   18470016983   18470016983   185   18470016983		- · ·			- · · ·				İ		
R130 184700108P80   Composition: 1.86 nome ±5%, 1/4 w.   R131 194700108P87   Composition: 270 ohnse ±5%, 1/4 w.   R132 194700108P87   Composition: 220 ohnse ±5%, 1/4 w.   R133 194700108P87   R134 194700108P87   R134 19470019P87   R134 194700108P87   R135 194700108P87   R135 194700108P87   R13700108P87   R13700108P87   R136 194700108P87   R13700108P87   R13700108P87   R138 194700108P87   R13700108P87   R13700108P87   R139 194700108P87   R13700108P87   R13700108P87   R130 194700108P87   R13700108P87   R13700108P87   R131 194700108P87   R13700108P87   R13700108P87   R132 194700108P87   R13700108P87   R13700108P87   R133 194700108P87   R13700108P87   R13700108P87   R131 194700108P87   R13700108P87   R13700108P87   R131 194700108P87   R13700108P87   R132 194700108P87   R13700108P87   R13700108P87   R132 194700108P87   R13700108P87   R1370018P87   R133 194700108P87   R1370018P87   R133 194700108P87   R1370018P87   R133 194700108P87   R1370018P87   R131 194700108P87   R1370018P87   R131 194700108P87   R1370018P87   R131 194700108P87   R1370018P87   R132 194700108P87   R1370018P87   R132 194700108P87   R1370018P87   R132 194700108P87   R1370018P87   R132 194700108P87   R1370018P87   R132 194700108P87   R1370018P87   R132 19470018P87   R1370018P87   R134 19470018P87   R131 19470018P87   R134 19	I i i		1		<u>"</u>	i i				19A134753P5	Machine screw. (Secures R630 knob).
194700108P50   19470018P50   19		- · ·	R614	19A700019P44	Deposited carbon: 3.9K ohms ±5%, 1/4 w.	1		Regulator: 8.5 V.	1	19J706076P1	Washer, spring. (Secures R630 knob).
R133 19A700108P87 Composition: 580 ohms :55, 1/4 w. R610 19A700108P8 R401 19A700108P5 Composition: 1.3K ohms :55, 1/4 w. R619 R403 19A700108P8 R403 19A700108P3 R404 19A700108P8 R405 19A700108P8 R406 19A70019P8 Page R406 R406 R406 R406 R406 R406 R406 R406	1 1	<del>-</del> '	R615	19A700019P57	Deposited carbon: 47K ohms ±5%, 1/4 w.			_		1	Washer. (Secures R630 knob).
R401 19A700106P65 Composition: 1.2K ohms ±5K, 1/4 w.  R402 19A700106P75 Composition: 3.3K ohms ±5K, 1/4 w.  R403 19A700106P75 Composition: 3.3K ohms ±5K, 1/4 w.  R404 19A700106P39 Composition: 100 ohms ±5K, 1/4 w.  R405 19A70019P56 Deposited carbon: 39K ohms ±5K, 1/4 w.  R406 19A70019P57 Pack of the printed board 19A70019P50 Deposited carbon: 39K ohms ±5K, 1/4 w.  R406 19A70019P57 Pack of the printed board 19A70019P50 Deposited carbon: 39K ohms ±5K, 1/4 w.  R407 19A70019P57 Pack of the printed board 19A70019P50 Deposited carbon: 47K ohms ±5K, 1/4 w.  R407 19A70019P51 Deposited carbon: 220 ohms ±5K, 1/4 w.  R409 19A70019P51 Deposited carbon: 220 ohms ±5K, 1/4 w.  R400 19A70019P52 Deposited carbon: 220 ohms ±5K, 1/4 w.  R401 19A70019P52 Deposited carbon: 220 ohms ±5K, 1/4 w.  R402 19A70019P54 Pack of the printed board 19A70019P54 Deposited carbon: 220 ohms ±5K, 1/4 w.  R402 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R403 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R405 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R406 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R407 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R408 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R409 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R400 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R401 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R402 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R403 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R404 19A70019P54 Deposited carbon: 27K ohms ±5K, 1/4 w.  R405 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbon: 19A70019P54 Deposited carbo	1 1		R616	19A700019P49	Deposited carbon: 10K ohms ±5%, 1/4 w.			******	İ	19A702364P208	Machine screw: TORX®Drive, M2.5 - 0.45 x 8. (Secures Q110, U601 & U602).
R402 194700106P75   Composition: 3.3K ohms ±55, 1/4 w.   R619   194700106P30   R405   194700106P30   R405   194700106P30   R406   194700106P30   R406   194700106P30   R407   194700106P30   R409   194700106P30   R409   194700106P30   R501   194700106P30   R602   R602			R617	19A700019P68	Deposited carbon: 0.39M ohms ±5%, 1/4 w.	thru				19A700034P3	Hex nut, metric: M2.5 x 0.45. (Secures Q110,
R403 19A70010F083   R404 19A70010F093   R405   19A70010F094   R405   19A70010F095   R406   19A70010F095   R406   19A70010F095   R406   19A700019F091   R609   19A700019F091   19A70	1		R618	19A700019P50	Deposited carbon: 12K ohms ±5%, 1/4 w.	1		Microstrin industry (Post of suisted board		19470003203	
R404 19A700106P39		- · ·		19A700019P54	Deposited carbon: 27K ohms ±5%, 1/4 w.	thru		19D900231P1).	1	194700032F3	Lockwasher, tooth, steel, metric: 2.5. (Secures Q110, U601 & U602).
R405 19A700019P56 R406 19A700019P57 Deposited carbon: 39K ohms ±5%, 1/4 w.  R407 19A700019P29 Deposited carbon: 220 ohms ±5%, 1/4 w.  R409 19A700019P31 Deposited carbon: 330 ohms ±5%, 1/4 w.  R501 19A700019P54 Deposited carbon: 220 ohms ±5%, 1/4 w.  R501 19A700019P54 Deposited carbon: 22K ohms ±5%, 1/4 w.  R502 R502 R627 R6278 R6278 R6278 R6278 R6278 R6278 R628 R6278 R628 R6278 R628 R628 R628 R628 R628 R628 R628 R62	1 1	_ · · ·				1		Microstrin industor (Part of printed board		19A701312P3	Flatwasher, metric: No. 2.5MM. (Secures Q110 & U602)
R406 19A700019P57 Deposited carbon: 47K ohms ±5%, 1/4 w.  R407 19A700019P29 Deposited carbon: 220 ohms ±5%, 1/4 w.  R409 19A700019P31 Deposited carbon: 330 ohms ±5%, 1/4 w.  R501 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w.  R502 and R503 P503 P503 P503 P503 P503 P503 P503 P	1	-	R621	19A700019P40	Deposited carbon: 1.8K ohms <u>+</u> 5%, 1/4 w.	,,,,,,			1	19A702364P106	Machine screw: TORX®Drive, No. M2 - 0.4 x 6.
R407	1 1	<del>-</del> · · ·	R622	19A700019P31	Deposited carbon: 330 ohms ±5%, 1/4 w.				1		
R409 194700019P31 Deposited carbon: 330 ohms ±5%, 1/4 w. R501 194700019P53 Poposited carbon: 22K ohms ±5%, 1/4 w. R502 and R503 Poposited carbon: 27K ohms ±5%, 1/4 w. Deposited carbon: 27K ohms ±5%, 1/4 w. Deposited carbon: 27K ohms ±5%, 1/4 w. R627 R627 R627 Poposited carbon: 220 ohms ±5%, 1/4 w. R628 Poposited carbon: 200 ohms ±5%, 1/4 w. R628 Poposited carbon: 200 ohms ±5%, 1/4 w. R629 Poposited carbon: 200 ohms	R407 19A700019P29	Deposited carbon: 220 ohms ±5%, 1/4 w.	1 1	1		X501		}		19A138451P2	Spring. (Used with L401-L405, L407, & L408).
R501 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w.  R502 and R503 Peoposited carbon: 27K ohms ±5%, 1/4 w.  Deposited carbon: 27K ohms ±5%, 1/4 w.  Deposited carbon: 27K ohms ±5%, 1/4 w.  R627 R627 R627B and R628 R628 And R628A Peoposited carbon: 150 ohms ±5%, 1/4 w.  R628 R627 Peoposited carbon: 150 ohms ±5%, 1/4 w.  NOTE: When reordering give GE Part Number and specify exact frequency needed.  Y501 19B2330669 Crystal: freq range 45.4675 MHz.	1 1	<u>-</u> · · ·	1 1		_		19A702742P1				
R502 and R503   19A700019P54   Deposited carbon: 27K ohms ±5%, 1/4 w.   R627A   19A700019P29   Deposited carbon: 220 ohms ±5%, 1/4 w.   R627B and R628A   19A700019P27   Deposited carbon: 150 ohms ±5%, 1/4 w.   NOTE: When reordering give GE Part Number and specify exact frequency needed.   Y501   19B23306669   Crystal: freq range 45.4675 MHz.	R501 19A700019P53	Deposited carbon: 22K ohms ±5%, 1/4 w.	and	19A7U0019P37	Deposited carbon: 1K ohms $\pm 5\%$ , 1/4 w.						
R627B and R628A R6		Deposited carbon: 27K ohms ±5%, 1/4 w.		10.4700010-00	Barrada da sunhan anna an an an an				1		
and R628A  Y501 19B233066G9 Crystal: freq range 45.4675 MHz.			1 1		<del>-</del> ' '				1		
Y501 19B233066G9 Crystal: freq range 45.4675 MHz.			and	198100019551	Deposited caroon: 150 ohms ±5%, 1/4 w.				1		
Deposited carbon. 100 olims Toe, 1/4 W.			1	194700019222	Denosited carbon: 190 obmo 459 1/4 -	¥501	19B233066G9	Crystal: freq range 45.4675 MHz.		1	
				2011.00010F20	- 2-розгоса сагоси. 100 опш <b>s том, 1/4 w.</b>						
									1		
										1	

LBI31004

# PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A Transmit/Receive Board 19D900232G2, 3

  To eliminate alternator whine. Deleted C615.
- REV. A Transmit/Receive Board 19D900232G1
- REV. B Transmit/Receive Board 19D900232G2, 3

To improve operation of 2nd local oscillator Ckt. Changed R511 and C508. C508 was: 19A700235P21, 47 pf ceramic disc. 50 volt. R511 was: 19A700019P45, 4700 ohms, carbon film. 1/4 Watt.

- REV. A Transmit/Receive Board 19D900232G5,6
- REV. C Transmit/Receive Board 19D900232C2,3
  To improve operation. Deleted C11 and T101. Changed C112 and added L120.
  C112 was:
  19A700219P48 Ceramic: 36pF ±5%, 100 VDCW, temp coef 0 PPM.
- REV. D 19D900232C2,3 15-Watt Transmit/Receive Board REV. B 19D900232C4-6 15-Watt Transmit/Receive Board

To improve low end audio frequency response (300 Hertz) Changed C607 from 10 Nanofarads to 15 Nanofarads. Part Number for C607 was: 194700234P7 Polyester: 0.01 uF ±10% 50 VDCW.

- REV. E 15 Watt Transmit/Receive Board 19D90023262,3
  REV. C 15 Watt Transmit/Receive Board 19D90023265,6
  To improve operation of audio circuit. Changed R647.
  Part number for R647 was:
  19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4W.
- REV. F 15 Watt Transmit/Receive Board 19900023262.3

  REV. D 15 Watt Transmit/Receive Board 19900023265.6

  To improve operation of Q106 and provide compatabilit for future options Changed R120\_R122 Added D103

15 watt Transmit/Receive Board 19D900232G5,6
To improve operation of Q106 and provide compatability
for future options. Changed R120-R122. Added D103
and holes H9-H12. DA jumpers are connected between
H9-H10 and H11-H12. Part numbers were:
R120-3R152P241J Composition: 240 ohms ±5% 1/4W.
R121-3R152P621J Composition: 620 ohms ±5% 1/4W.
R122-19A700106P23 Composition: 22 ohms ±5% 1/4W.